

### Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated chip junction
- High surge forward current capability
- Ideal for automated placement
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2015/863/EU

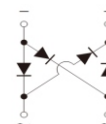
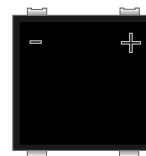
### Mechanical data

- Case:JBF molded plastic body
- Terminals:Plated leads solderable per MIL-STD-750,method 2026
- Polarity:As marked
- Mounting Position:Any

### APPLICATIONS

- Used in high frequency AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

JBF



HALOGEN  
**FREE**

### Maximum Ratings And Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

Parameters	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	1000	V
Maximum average forward rectified current	$I_{F(AV)}$	4.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	140	A
Rating for fusing( $t=8.3ms$ )	$I^2t$	81.3	A <sup>2</sup> S
Operating junction temperature range	$T_j$	-55 to 150	°C
Storage temperature range	$T_{stg}$	-55 to 150	°C

## Electrical Characteristics (Per diode, $T_A=25^{\circ}\text{C}$ Unless otherwise noted)

Parameter	Test Conditions		Symbol	Min.	Typ.	Max.	Unit
Breakdown voltage Blocking voltage	I <sub>b</sub> =10μA		V <sub>BR</sub> V <sub>R</sub>	1050	-	-	V
Instaneous forward voltage	T <sub>J</sub> =25℃	I <sub>f</sub> =1.0A	V <sub>F</sub> <sup>1)</sup>	-	0.83	-	V
		I <sub>f</sub> =4.0A		-	0.93	1.00	
	T <sub>J</sub> =125℃	I <sub>f</sub> =1.0A		-	0.70	-	
		I <sub>f</sub> =4.0A		-	0.81	0.87	
		Reverse current		T <sub>J</sub> =25℃	V <sub>R</sub> =1000V	I <sub>R</sub> <sup>2)</sup>	
T <sub>J</sub> =125℃	-		-	250			
Junction capacitance	4V,1MHz		C <sub>J</sub>	-	49	-	pF

Notes: 1.Pulse test: 300  $\mu\text{s}$  pulse width,1% duty cycle

2.Pulse test: pulse width  $\leq 40\text{ms}$

## Thermal Characteristics

Parameter	Symbol	JBF	Unit
Typical thermal resistance <sup>3)</sup>	$R_{\theta JC}$	5.0	$^{\circ}\text{C/W}$

3.Thermal resistance from per diode junction to case

Fig.1-Forward Current Derating Curve

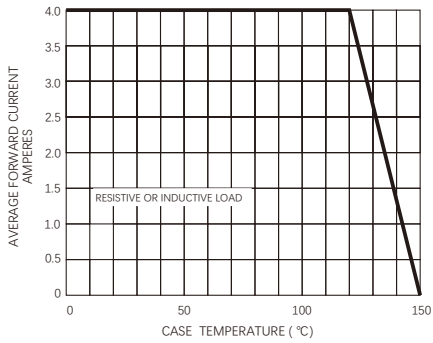


Fig.2-Maximum Non-repetitive Peak Forward Surge Current

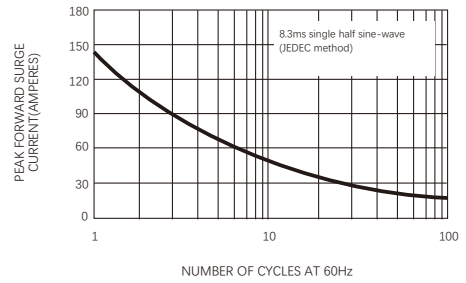


Fig.3-Typical Instantaneous Forward Characteristics

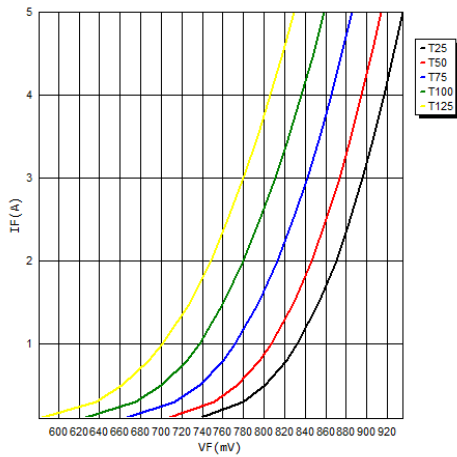
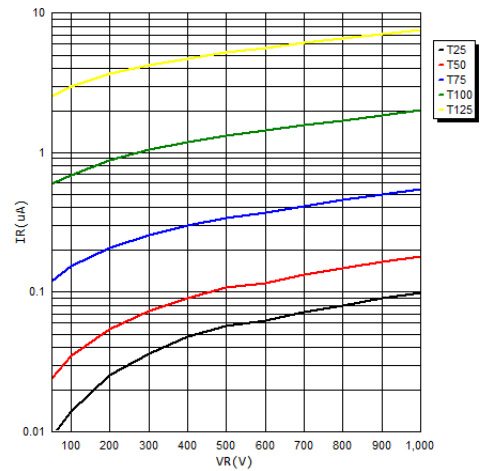
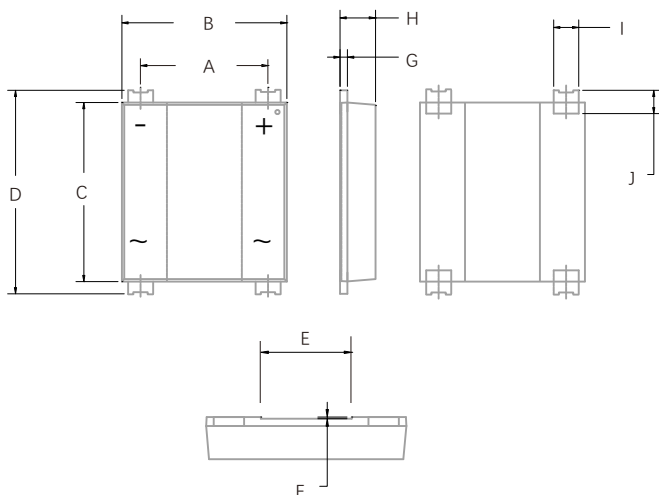


Fig.4-Typical Reverse Characteristics

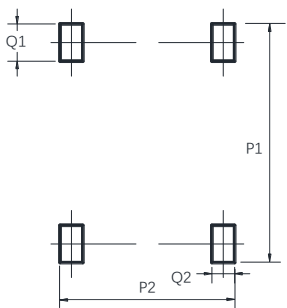


JBF



UNIT:mm		
DIM	MIN	MAX
A	4.80	5.30
B	6.20	7.00
C	7.10	8.20
D	7.90	8.90
E	2.90	3.10
F	0.04	0.08
G	0.15	0.40
H	1.30	1.50
I	0.80	1.20
J	0.70	1.60

Suggested Pad layout



Dimensions in millimeters

Dim	Min
P1	9.15
P2	7.10
Q1	1.80
Q2	2.00

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